

# Ultrahigh-Definition CRT Display Video Output Applications

## **Applications**

- · Ultrahigh-definition CRT display.
- · Video output.
- · Color TV chroma output.
- · Wide-band amp.

#### **Features**

- · High  $f_T$ :  $f_T$  typ=400MHz.
- · High breakdown voltage : V<sub>CEO</sub>≥200V.
- · Small reverse transfer capacitance and excellent high-frequency characteristic
  - : C<sub>re</sub>=2.0pF (NPN), 2.5pF (PNP).
- · Complementary PNP and NPN types.
- · Adoption of FBET process.

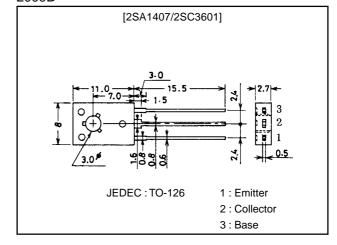
(): 2SA1407

# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

unit:mm

2009B



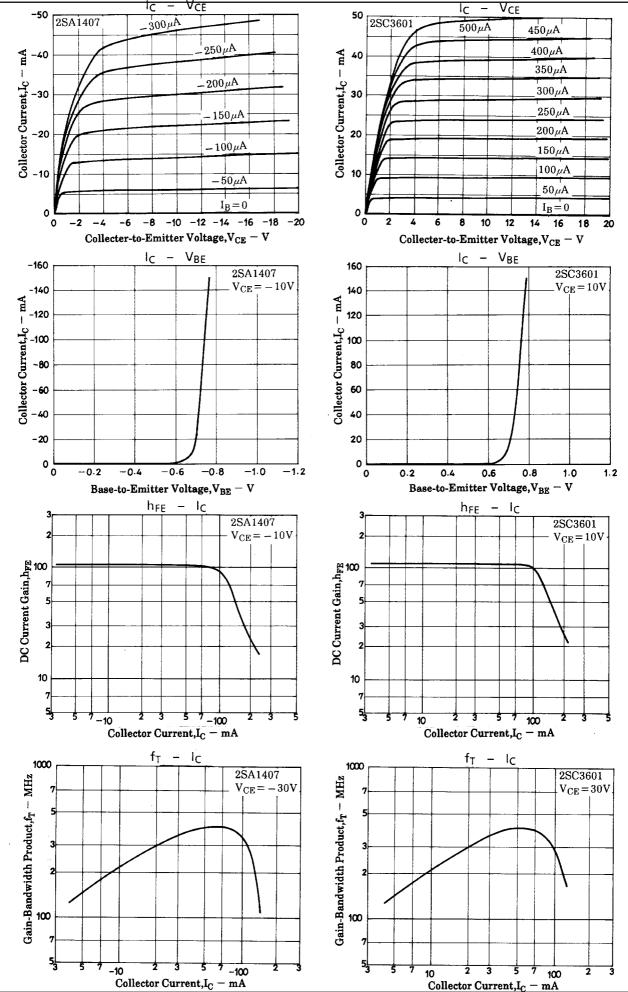
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)200	V
Collector-to-Emitter Voltage	VCEO		(-)200	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)4	V
Collector Current	IC		(-)150	mA
Collector Current (Pulse)	I <sub>CP</sub>		(-)300	mA
Collector Dissipation	PC		1.2	W
		Tc=25°C	7	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

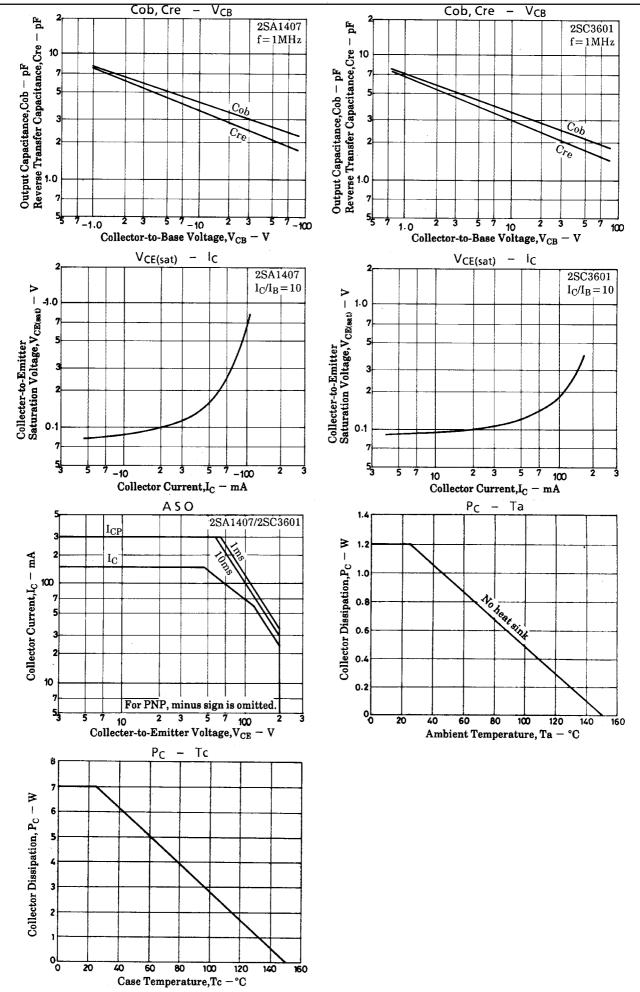
#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Unit		
Falametei	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)150V, I <sub>E</sub> =0			(–)0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)2V, I <sub>C</sub> =0			(-)1.0	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)10mA	40*		320*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)100mA	20			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)30V, I <sub>C</sub> =(-)50mA		400		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)50mA, I <sub>B</sub> =(-)5mA			0.6	V
					(-0.8)	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =(-)5mA			(-)1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μΑ, I <sub>E</sub> =0	(-)200			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)200			V
Emitter-to-Base Breakdown Votage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)100μΑ, I <sub>C</sub> =0	(-)4			V
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.5		pF
				(3.0)		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		2.0		pF
				(2.5)		pF

 $\mbox{*}$  : The 2SA1407/2SC3601 are classified by 10mA  $\mbox{h}_{FE}$  as follows :

40		00	60	_	120	100		200	160	 220
40	C	80	60	D	120	100	E	200	160	 320





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